TDA7454

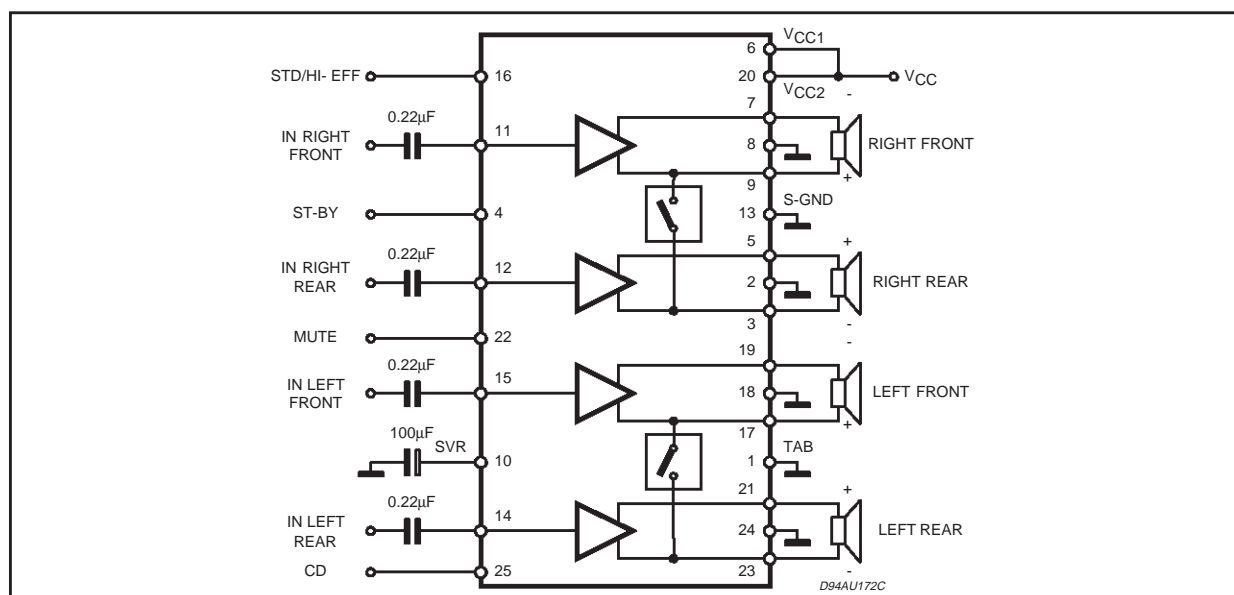## 4 x 35W HIGH EFFICIENCY QUAD BRIDGE CAR RADIO AMPLIFIER

- HIGH OUTPUT POWER CAPABILITY:
  4 x 40W/4Ω MAX.
  4 x 35W/4Ω EIAJ.
  4 x 25W/4Ω @14.4V, 1KHz, 10%
  4 x 60W/2Ω MAX.
- 2Ω DRIVING CAPABILITY
- DUAL MODE OPERATING EXTERNALLY PRESETTABLE: CONVENTIONAL CLASS A-B MODE, HIGH EFFICIENCY MODE
- LOW EXTERNAL COMPONENTS COUNT:
  – NO BOOTSTRAP CAPACITORS
  – NO EXTERNAL COMPENSATION
  – INTERNALLY FIXED GAIN (26dB)
- CLIPPING DETECTOR
- ST-BY FUNCTION (CMOS COMPATIBLE)
- MUTE FUNCTION (CMOS COMPATIBLE)
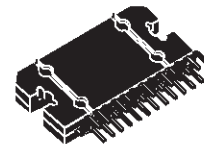- AUTOMUTE AT MINIMUM SUPPLY VOLTAGE DETECTION
- LOW RADIATION

Protections:
- OUPUT SHORT CIRCUIT
  TO GND; TO V_S; ACROSS THE LOAD
- 3 STEPS OVERRATING CHIP TEMPERATURE WITH THERMAL WARNING
- LOAD DUMP VOLTAGE
- FORTUITOUS OPEN GND

MULTIPOWER BCD TECHNOLOGY

Flexiwatt 25

- LOUDSPEAKER DC CURRENT
- ESD

DESCRIPTION

The TDA7454 is a new BCD technology QUAD BRIDGE type of car radio amplifier in Flexiwatt25 package specially intended for car radio applications. Among the features, its superior efficiency performance coming from the internal exclusive structure, makes it the most suitable device to simplify the thermal management in high power sets. The dissipated output power under average listening condition is in fact reduced up to 50% when compared to the level provided by conventional class AB solutions.
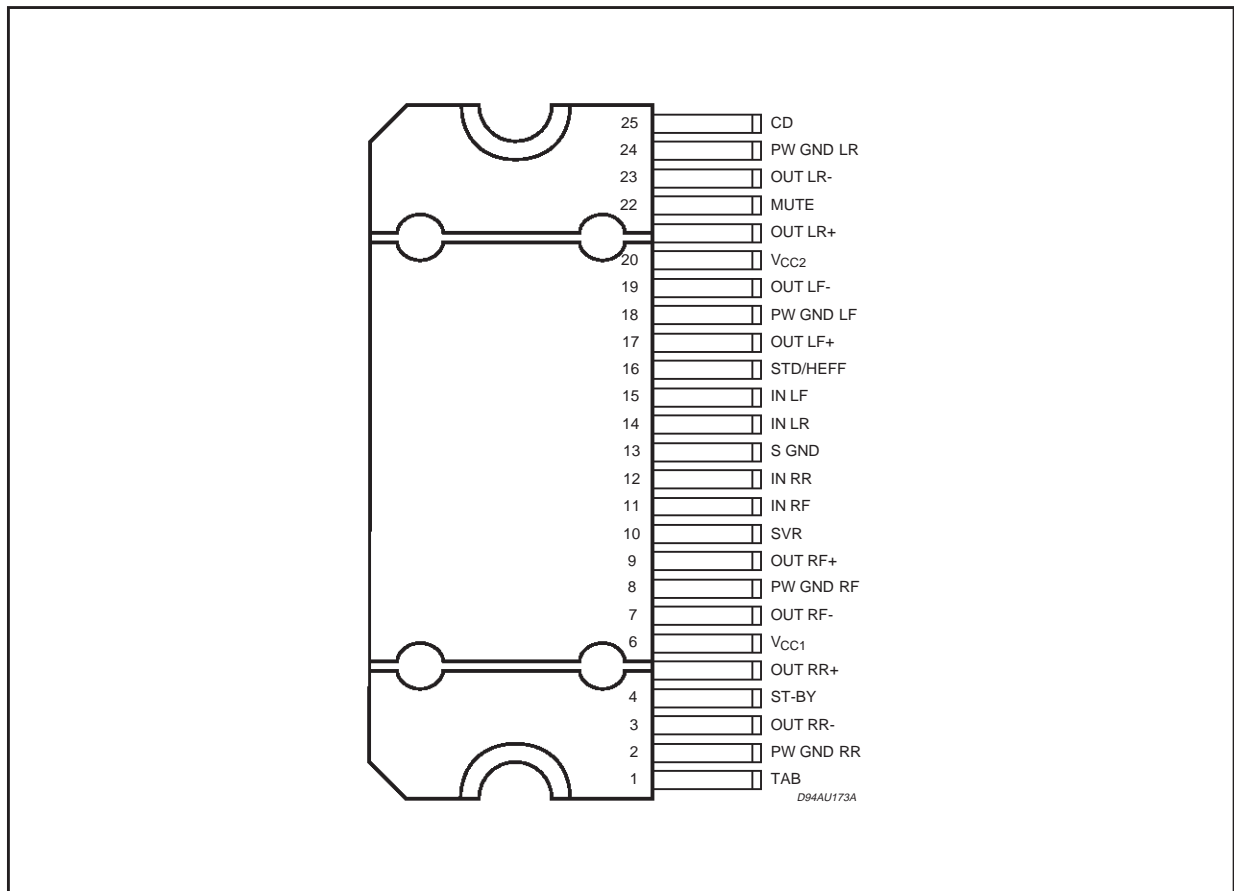
BLOCK & APPLICATION DIAGRAM

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{op}	Operating Supply Voltage	18	V
V_S	DC Supply Voltage	28	V
V_{peak}	Peak Supply Voltage (for t = 50ms)	40	V
I_O	Output Peak Current (not repetitive t = 100µs)	8	A
I_O	Output Peak Current (repetitive f > 10Hz)	6	A
P_{tot}	Power Dissipation T_{case} = 70°C	86	W
T_{stg}, T_j	Storage and Junction Temperature	-55 to 150	°C

THERMAL DATA

Symbol	Description		Value	Unit
$R_{th\ j-case}$	Thermal Resistance Junction-case	Max	1	°C/W

PIN CONNECTION (Top view)

Pin	Signal
25	CD
24	PW GND LR
23	OUT LR-
22	MUTE
	OUT LR+
20	V_{CC2}
19	OUT LF-
18	PW GND LF
17	OUT LF+
16	STD/HEFF
15	IN LF
14	IN LR
13	S GND
12	IN RR
11	IN RF
10	SVR
9	OUT RF+
8	PW GND RF
7	OUT RF-
6	V_{CC1}
	OUT RR+
4	ST-BY
3	OUT RR-
2	PW GND RR
1	TAB

D94AU173A

ELECTRICAL CHARACTERISTICS (Refer to the test circuit V_S = 14.4V; R_L = 4Ω; f = 1KHz; T_{amb} = 25°C, unless otherwise specified

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
V_S	Supply Voltage Range		8		18	V
I_d	Total Quiescent Drain Current		60	140	250	mA
P_o	Output Power	THD = 10% THD = 1%	23 18	25 20		W W
		THD = 10% RL = 2Ω; THD = 1% R_L = 2Ω;	40 28	42 30		W W
$P_{o\ EIAJ}$	EIAJ Output Power (*)	Vs = 13.7V Vs = 13.7V, RL = 2Ω	32 50	35 52		W W
$P_{o\ max.}$	Max. Output Power (*)	Vs = 14.4V Vs = 14.4V, RL = 2Ω	38 55	40 60		W W
THD	Total harmonic distortion	P_O = 1W to 10W; STD MODE P_O = 1W; HE MODE P_O = 10W; HE MODE		0.03 0.04 0.1	0.3 0.3 0.5	% % %
		R_L = 2Ω; HE MODE; P_O = 3W R_L = 2Ω; HE MODE; P_O = 15W		0.06 0.15	0.3 0.5	% %
C_T	Cross Talk	f = 1KHz to 10KHz	45	55		dB
R_{IN}	Input Impedance		11	15	19	KΩ
G_V	Voltage Gain		25	26	27	dB
ΔG_V	Voltage Gain Match				1	dB
E_{IN}	Output Noise Voltage	R_g = 600Ω		100	150	μV
SVR	Supply Voltage Rejection	f = 300Hz; Vr = 1Vrms; R_g = 0 to 100Ω;	45	52		dB
BW	Power Bandwidth	(−3dB)	75			KHz
A_{SB}	Stand-by Attenuation		90	100		dB
$V_{sb\ IN}$	Stand-by in Threshold				1.5	V
$V_{sb\ OUT}$	Stand-by out Threshold		3.5			V
I_{sb}	Stand-by Current Consumption				50	μA
A_M	Mute Attenuation		80	90		dB
$V_{M\ IN}$	Mute in Thereshold				1.5	V
$V_{M\ OUT}$	Mute out Threshold		3.5			V
I_M	Mute pin Current (Sourced)	V = 0 to V_S $V_{S\ max}$ = 18V	-10	1	10	μA
	Mode Select Switch	Standard BTL Mode Op. ($V_{pin\,16}$)		Open		
		High Efficiency Mode ($V_{pin\,16}$)			0.5	V
CD	Clip Det. out Current (Pull up to 5V with 10KΩ)	CD off: P_{Omin} = 10W CD on: THD = 5%		150	5	μA μA

(*) Saturated square wave output.
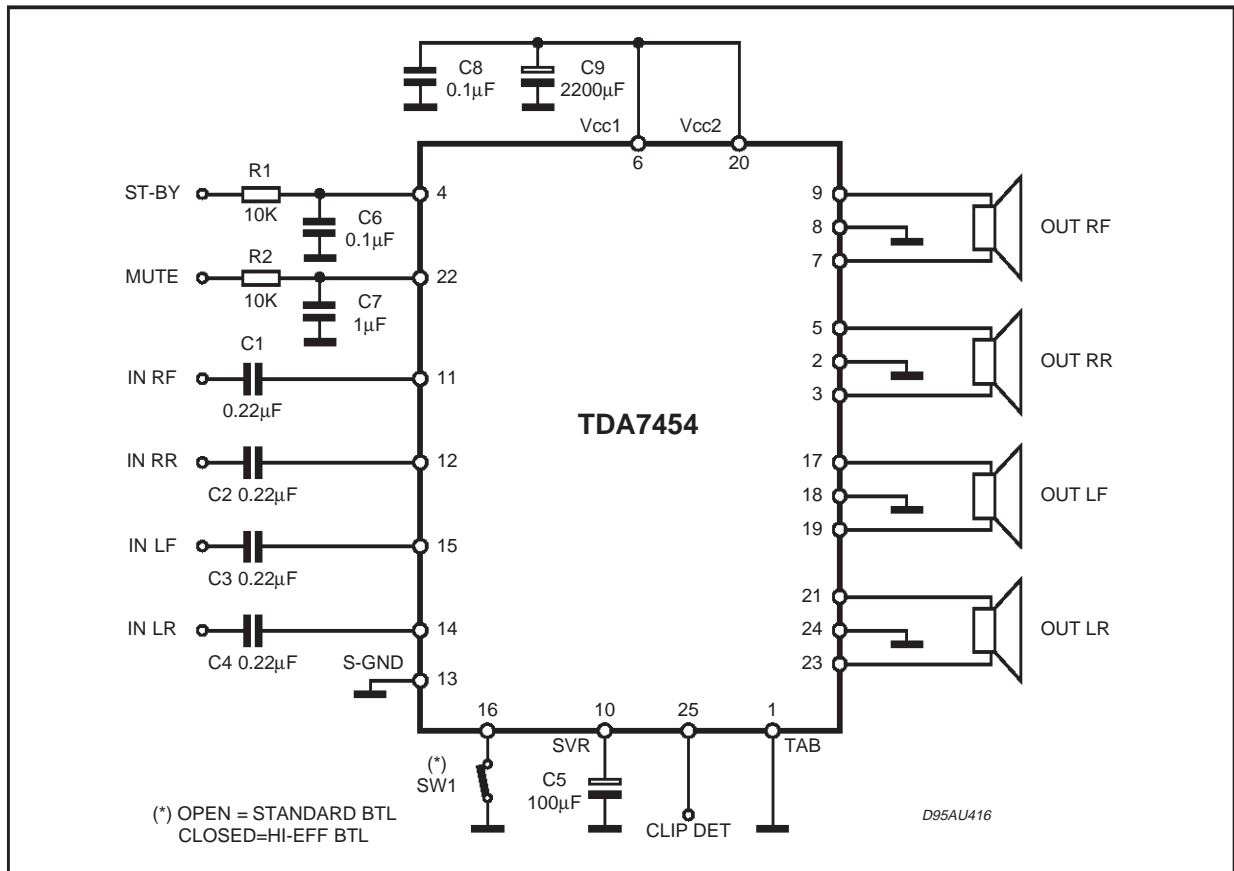
Figure 1: Standard Test and Application Circuit.

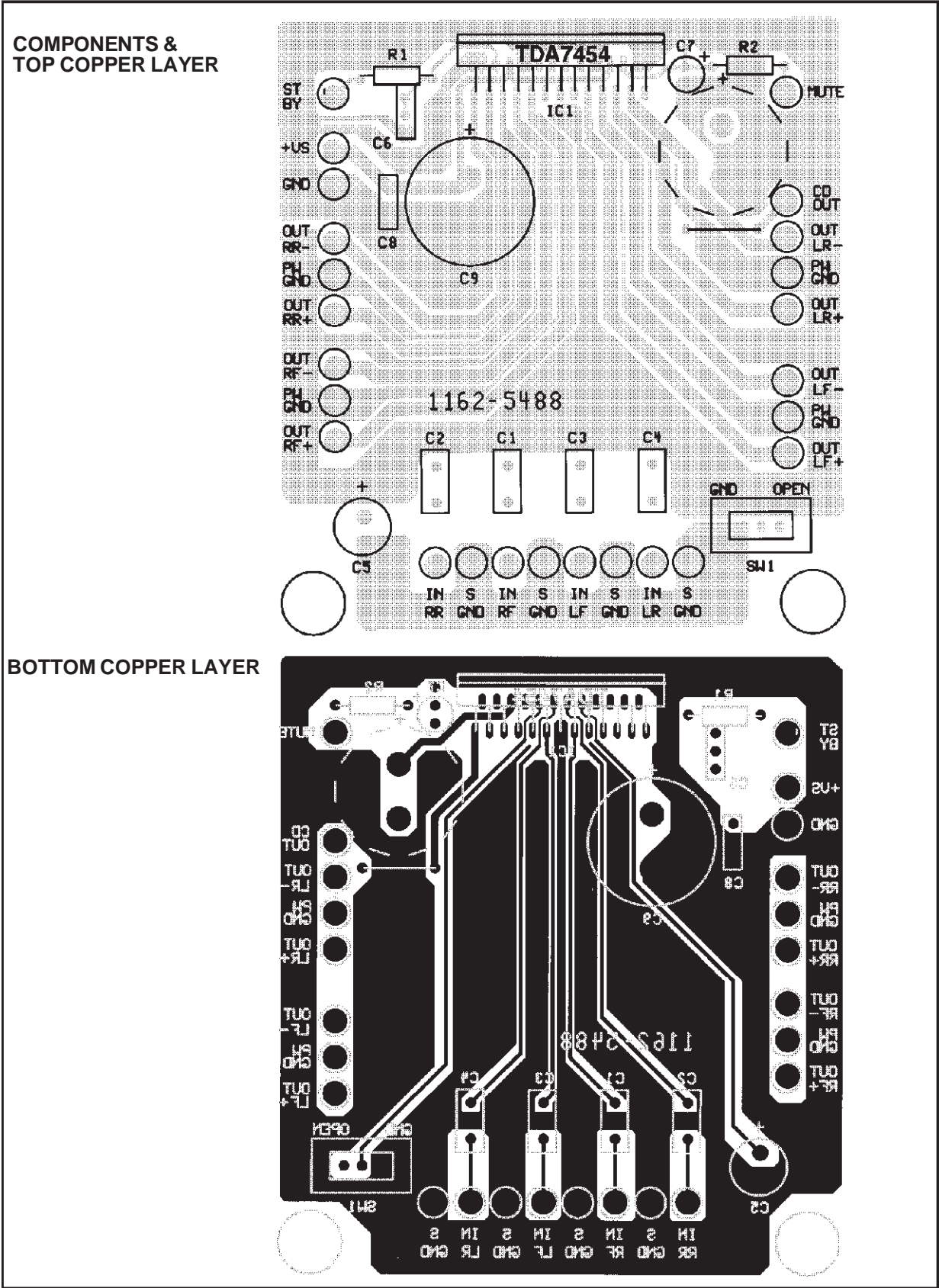**Figure 2:** P.C.B. and components layout of fig. 1 circuit. (1.25 :1 scale)

COMPONENTS &
TOP COPPER LAYER

BOTTOM COPPER LAYER

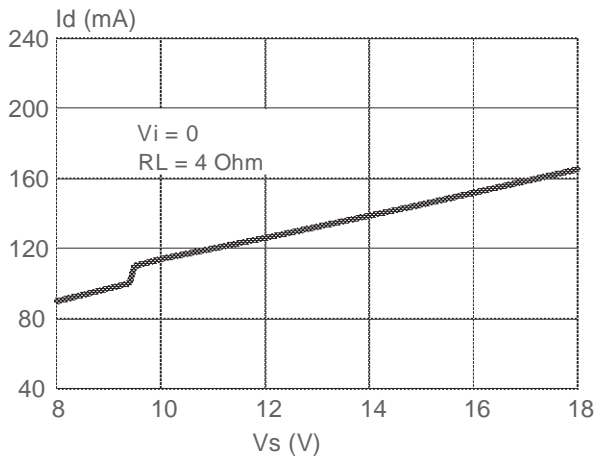**Figure 3:** Quiescent Current vs. Supply Voltage

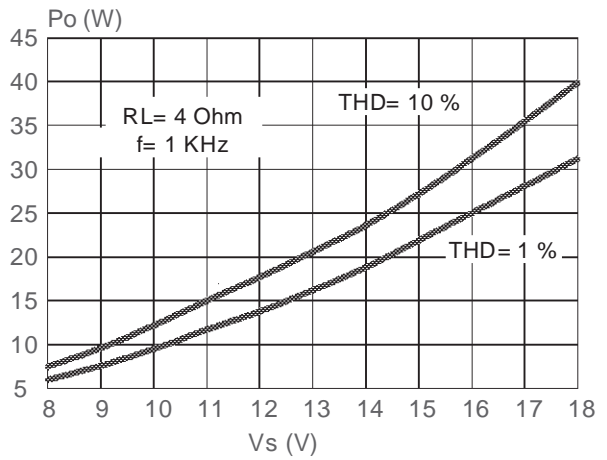**Figure 4:** Output Power vs. Supply Voltage
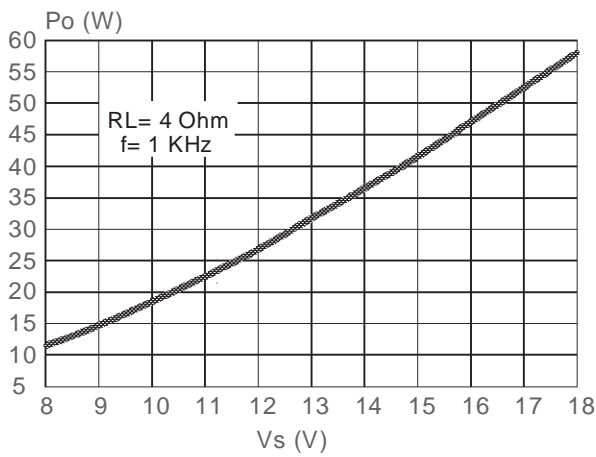

Figure 5: Max. Output Power vs. Supply Voltage

Figure 6: Output Power vs. Supply Voltage
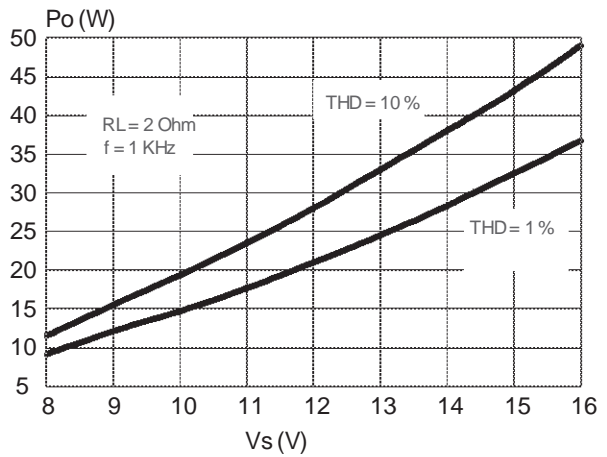

Figure 7: Max. Output Power vs. Supply Voltage
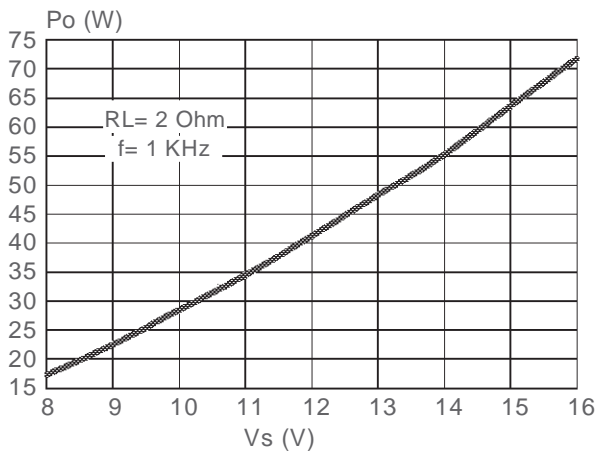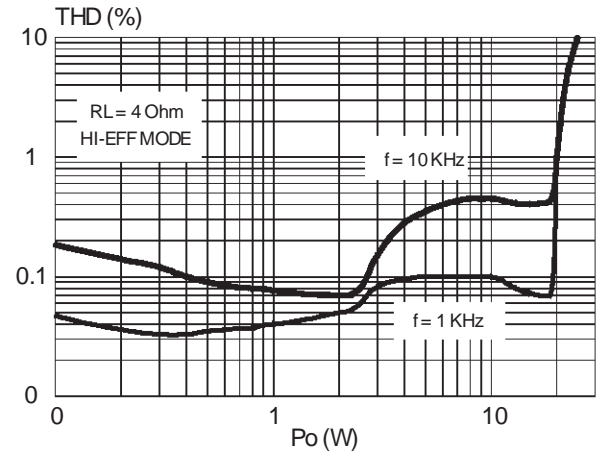

Figure 8: THD vs. Output Power

Figure 9: THD vs. Output Power

THD (%)

RL = 2 Ohm
HI-EFF MODE

f = 10 KHz

f = 1 KHz

Po (W)
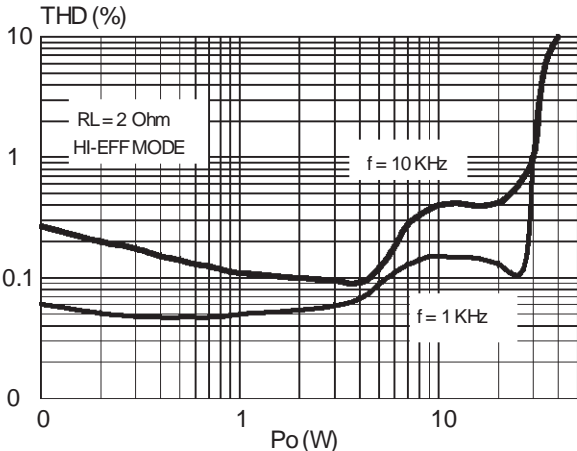
Figure 10: Muting Attenuation vs. Vpin 22

OUT ATTN

Po= 4 W
f= 20 to 20,000 Hz

Vpin22 (V)
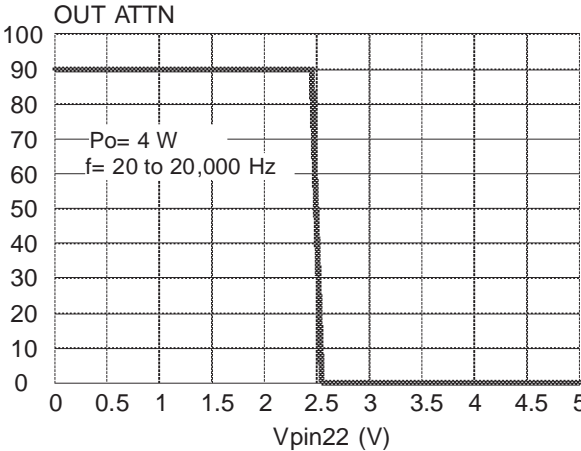
Figure 11: THD vs. Frequency

THD (%)

RL = 4 Ohm
Po = 1 W
HI-EFF MODE

f (Hz)
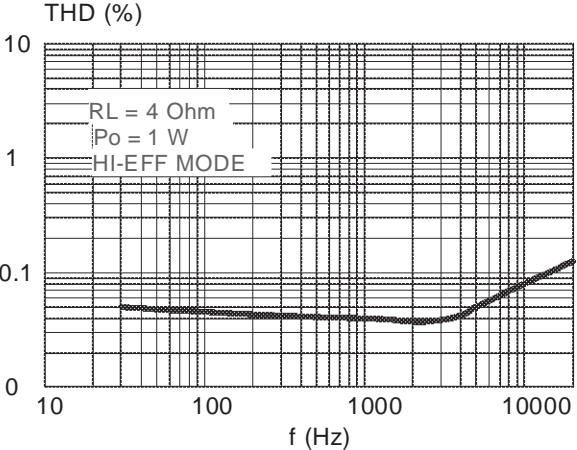
Figure 12: Supply Voltage Rejection vs. Frequency

SVR (dB)

Vripple= 1 Vrms
Rg= 0

f (Hz)
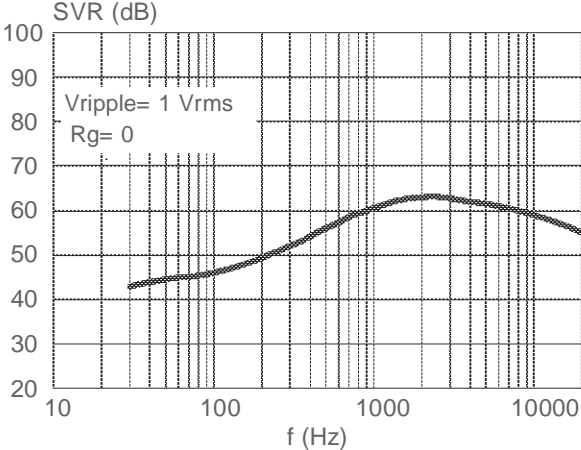
Figure 13: Cross-Talk vs. Frequency

CROSSTALK (dB)

Po = 4 W
RL = 4 Ohm
Rg = 0
HI-EFF MODE

f (Hz)
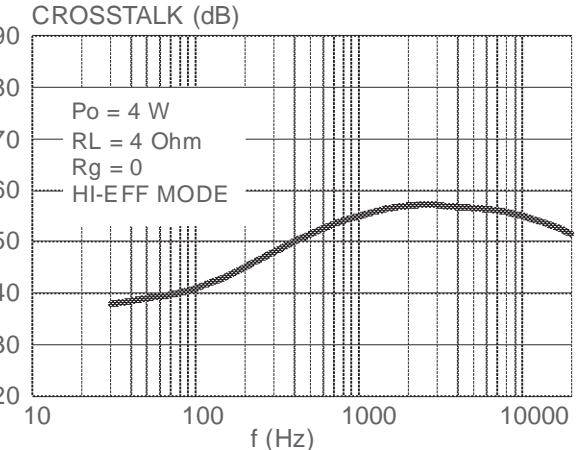
Figure 14: Power Dissipation and Efficiency vs. Output Power

Ptot (W)   n (%)

Vs= 14.4 V
RL = 4 x 4 Ohm
f = 1 KHz
HI-EFF MODE

n

Ptot

Po (W)
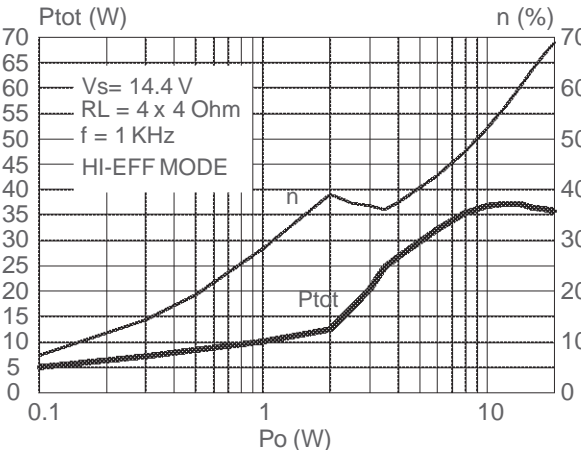
TDA7454

OPERATING PRINCIPLE.

Thanks to its unique operating principle, the TDA7454 obtains a substantial reduction of power dissipation from traditional class-AB amplifiers without being affected by the massive radiation effects and complex circuitry normally associated with class-D solutions.

Its is composed of 8 amplifier blocks, making up 4 bridge-equivalent channels. Half of this structure is drafted in fig 15. These blocks continuously change their connections during every single signal event, according to the instantaneous power demand. This means that at low volumes (output power steadily lower than 2.5 W) the TDA7454 acts as a Single Ended amplifier, condition where block "C" remains disabled and the block "D" behaves like a buffer, which, by furnishing the correct DC biasing (half-Vcc) to each pair of speakers, eliminate the needs of otherwise required output-decoupling capacitors. At the same time, SW1 keeps closed. thus ensuring a common biasing point for L-R front / L-R rear speakers couples. As a result, the equivalent circuit becomes that of fig. 16.

The internal switches (SW1) are high-speed, dissipation-free power MOS types, whose realization has been made possible by the ST- exclusive Bypolar-CMOS-DMOS mixed technology process (BCD). From fig. 16 it can be observed that "A" and "B" amplifiers work in phase opposition. Supposing their output have the same signal (equal shape/amplitude), the current sourced by "B" will be entirely sunk by "A", while no current will flow into "D", causing no power dissipation in the latter.

"A" and "B" are practically configured as a bridge whose load is constituted by Ra + Rb (= 8 Ohm, if 4 Ohm speakers are used), with considerable advantages in terms of power dissipation. Designating "A" and "B" for the reproduction of either FRONT or REAR sections of the same channel (LEFT or RIGHT), keeping the fader in centre position (same amplitude for FRONT and REAR sections) and using the same speakers, as it happens during most of the time, will transpose this best-case dissipation condition into practical applications.

To fully take advantage of the TDA7454's low-dissipation feature, it is then especially important to adopt some criteria in the channels assignment, using the schematic of fig. 1 as a reference. When the power demand increases to more than 2.5 W, all the blocks will operate as amplifiers, SW1 is opened, leading to the seemingly conventional bridge configuration of fig. 17.

The efficiency enhancement is based upon the concept that the average output power during the reproduction of normal music/speech programs will stand anywhere between 10 % and 15 % of the rated power (@ THD= 10 %) that the amplifier

can deliver. This holds true even at high volumes and frequent clipping occurrence.

Applied to the TDA7454 (rated power= 25 W), this will result into an average output level of 2.5 - 3 W in sine-wave operation, region where the dissipated power is about 50 % less than that of a traditional amplifier of equivalent power class (see TDA7454 vs. CLASS-AB characteristics, fig. 18). Equally favourable is the case shown by fig. 19, when gaussian-distributed signal amplitudes, which best simulates the amplifier's real working conditions, are used.

APPLICATION HINTS (ref. to the circuit of fig. 1)

STAND-BY and MUTING (pins 4 & 22)

Both STAND-BY and MUTING pins are CMOS-compatible. The current sunk by each of them is about 1 μA. For pop prevention it is essential that during TURN ON/OFF sequences the muting be preventively inserted before making stand-by transitions. But, if for any reason, either muting or stand-by are not used, they have to be connected to Vcc through a 100 Kohm (minimum) resistance.

The R-C networks values in fig. 1 (R1-C6 and R2-C7) are meant to be the minimum-necessary for obtaining the lowest pop levels possible. Any reductions (especially for R2-C7) will inevitably impair this parameter.

SVR (pin 10)

The duty of the SVR capacitor (C5) is double: assuring adequate supply-ripple rejection and controlling turn ON/OFF operations. Its indicated value (100 uF) is the minimum-recommended to correctly serve both the purposes.

INPUTS (pins 11-12-13-14)

The inputs are internally biased at half-Vcc level. The typical input impedance is 15 KOhm, which implies using Cin (C1-C2-C3-C4) = 220 nF for obtaining a theoretical minimum-reproducible frequency of 48 Hz (-3 dB). In any case, Cin values can be enlarged if a lower frequency bound is desired, but, at any Cin enlargement must correspond a proportional increase of Csvr (C5), to safeguard the on/off pop aspect.

The following table indicates the right values to be used for Cin and Csvr, whose operating voltage can be 10 V.

LOW FREQUENCY ROLL-OFF (-3dB)	Cin (μF)	Csvr (μF)
48	0.22	100
22	0.47	220
16	0.68	330
11	1	470

8/13

Table 1: MODE SELECTION TABLE OPERATION OF THE DEVICE

1) STD/HI-EFF (pin 16 = OPEN)

STANDARD QUAD BRIDGE MODE	HIGH-EFF QUAD BRIDGE MODE	STANDARD QUAD SINGLE-ENDED MODE	ST-BY MODE
100	150	170	→ Tchip (deg)

2) STD/HI-EFF (pin 16 = GND)

HIGH-EFF QUAD BRIDGE MODE	STANDARD QUAD SINGLE-ENDED MODE	ST-BY MODE
150	170	→ Tchip (deg)

3) STD/HI-EFF (pin 16 connected as shown in the figure below.

STANDARD QUAD BRIDGE MODE OR HIGH-EFF MODE (Theatsink dependent)	HIGH-EFF QUAD BRIDGE MODE	STANDARD QUAD SINGLE-ENDED MODE	ST-BY MODE
100	150	170	→ Tchip (deg)

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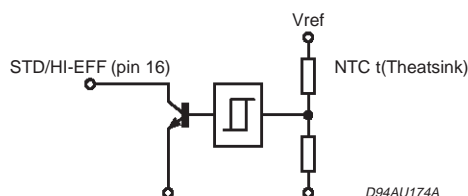
OUTPUT STAGE STABILITY

The TDA7454's is intrinsically stable and will properly drive any kind of conventional car-radio speakers without the need of supplementary output compensation (e.g. Boucherot cells), thus allowing a drastic reduction of the external parts whose number, abated to the essentials, reflects that of traditional amplifiers. In this respect, perfect pin-to-pin compatibility with the entire Sgs-Thomson's 4-BTL family (TDA738X) exists.

STANDARD / HIGH-EFFICIENCY OPERATION (pin 16)

The TDA7454's operating mode can be selected by changing the connection of pin 16, according to table 1.

At low battery levels (<10 V), the device will automatically turn into STANDARD BRIDGE mode, independently from the status of pin 16.

Condition # 3 in table 1 is particularly useful when the TDA7454's operation has to be conditioned by the temperature in other more heat-sensitive devices in the same environment. The NTC resistor is a temperature sensor, to be situated near the critical part(s), will appropriately drive pin 16 through a low-power transitor. Initially the TDA7454 can be set to operate as a STANDARD BRIDGE, turning into HIGH EFFICIENCY mode only if overheating is recognised in the critical spot, thus reducing the overall temperature in the circuit.

CLIPPING DETECTOR / DIAGNOSTIC (pin 25)

The TDA7454 is equipped with a diagnostic function whose output is available at pin 25. This pin requires a pull-up resistor (10 KOhm min.) to a DC source that may range from 5 V to Vcc. The following events will be recognized and signaled out:

Clipping
A train of negative-going pulses will appear, each of them syncronized with every single clipping event taking place in ant of the outputs.
A possible application consists of filtering / integrating the pulses and implement a routine for automatically reducing / restoring the volume using microprocessor - driven audioprocessors, to counteract the clipping sound-damaging effects.

Overheating
Chip temperatures above 150 oC will be signaled out at pin 25 in the form of longer-lasting pulses, as the stepping back into the operating temperature requires some time.

This constitues a substantial difference from the "clipping" situation, making the two information unmistakable. Associated to a suitable external circuitry, this "warning" signal could be used to mute some portions of the I.C. (e.g. the rear channels) or to attenuate the volume.

Short Circuit

Some kinds of short circuit (OUT - GND, OUT-Vcc), either present before the power-on or made afterwards, will cause pin 25 to remain steadily low as long as the faulty condition persists. Short-circuits across the speakers will give intermittent (pulsed) signalling, proportional to the output voltage amplitude.

External Layout Grounding

The 4 bridge stuctures have independent power ground accesses (pins 2,8,18,24), while the signal ground is common to all of them (pin 13). The

TAB (pin 1) is connected to the chip substrate and has to be grounded to the best-filtered ground spot (usually nearby the minus terminal of the Vcc-filtering electrolytic capacitor). This same point should be used as the centre of a multi-track star-like configuration, or, alternatively, as the origin of only two separate tracks, one for P-GND, one for S-GND, each of them routed to their specific ground pin(s).

This will provide the right degree of separation between P-GND and S-GND yet assuring the (necessary) electrical connection between them. The correct ground assignment for the each element of the circuit will then be:

POWER GND:

Battery (-), Supply filters (C8, C9), TAB (pin 1).

SIGNAL GND:

Pre-amplifier (Audiprocessor) ground, SVR capacitor (C5), muting/st-by capacitors (C6, C7).
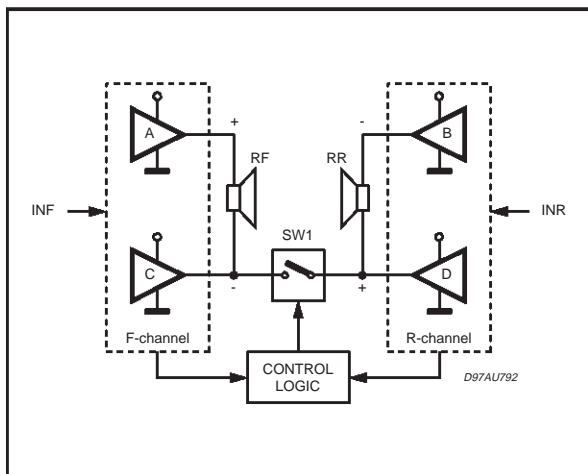
Figure 15: TDA7454's Half Structure
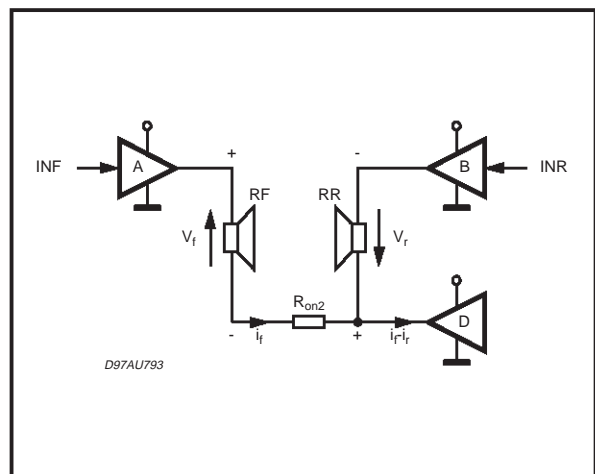

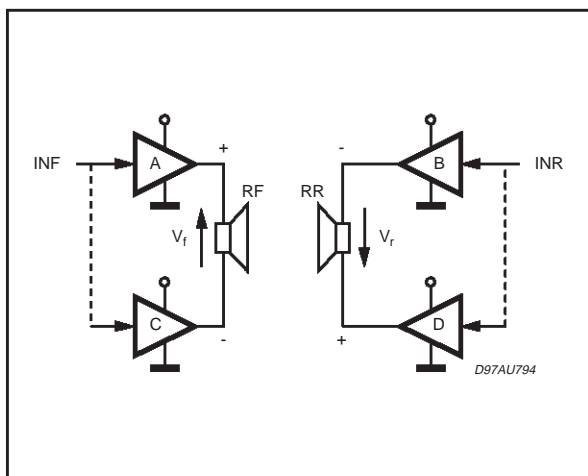**Figure 16:** Single Ended Operation (Po < 2.5W)

Figure 17: He Bridge Operation (Po < 2.5W)

Figure 18: Power Dissipation (Sine-Wave)
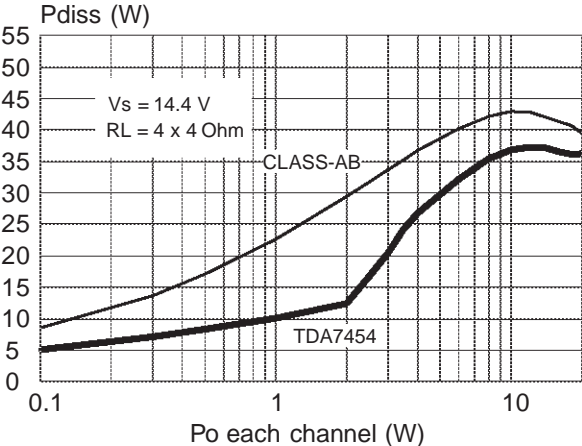
Pdiss (W)

Vs = 14.4 V
RL = 4 x 4 Ohm

CLASS-AB

TDA7454
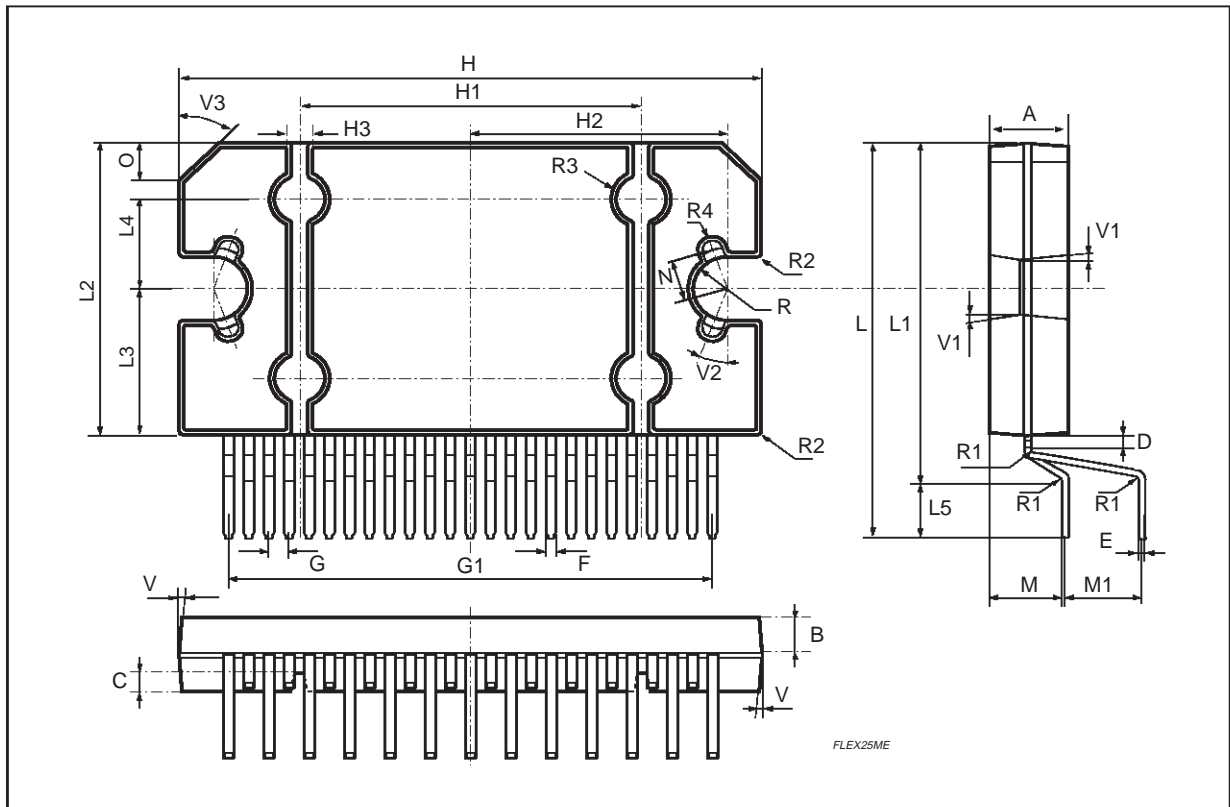
Po each channel (W)

Figure 19: Power Dissipation (Gaussian Signals)

Pdiss (W)

Vs = 14.4 V
RL = 4 x 4 Ohm

CLASS-AB

TDA7454

Pout each channel (W)
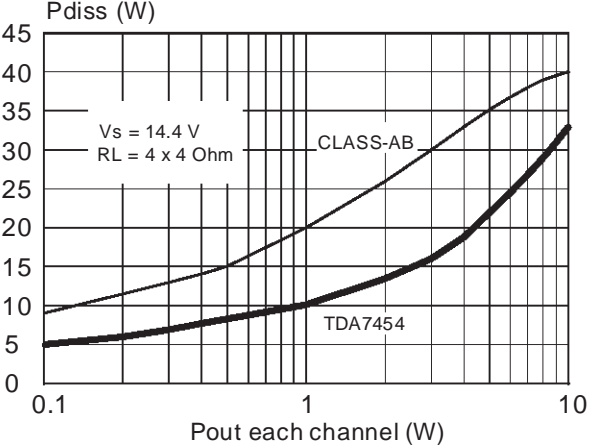
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.45	4.50	4.65	0.175	0.177	0.183
B	1.80	1.90	2.00	0.070	0.074	0.079
C		1.40			0.055	
D	0.75	0.90	1.05	0.029	0.035	0.041
E	0.37	0.39	0.42	0.014	0.015	0.016
F (1)			0.57			0.022
G	0.80	1.00	1.20	0.031	0.040	0.047
G1	23.75	24.00	24.25	0.935	0.945	0.955
H (2)	28.90	29.23	29.30	1.138	1.150	1.153
H1		17.00			0.669	
H2		12.80			0.503	
H3		0.80			0.031	
L (2)	22.07	22.47	22.87	0.869	0.884	0.904
L1	18.57	18.97	19.37	0.731	0.747	0.762
L2 (2)	15.50	15.70	15.90	0.610	0.618	0.626
L3	7.70	7.85	7.95	0.303	0.309	0.313
L4		5			0.197	
L5		3.5			0.138	
M	3.70	4.00	4.30	0.145	0.157	0.169
M1	3.60	4.00	4.40	0.142	0.157	0.173
N		2.20			0.086	
O		2			0.079	
R		1.70			0.067	
R1		0.5			0.02	
R2		0.3			0.12	
R3		1.25			0.049	
R4		0.50			0.019	
V	5° (Typ.)					
V1	3° (Typ.)					
V2	20° (Typ.)					
V3	45° (Typ.)					

(1): dam-bar protusion not included
(2): molding protusion included

OUTLINE AND MECHANICAL DATA

Flexiwatt25

FLEX25ME